



2N7002K

60V N-Channel Enhancement Mode MOSFET – ESD Protected

Voltage **60 V** **Current** **300mA**

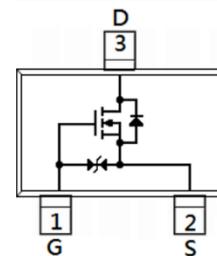
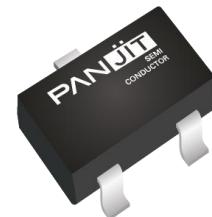
SOT-23

Features

- $R_{DS(ON)}$, $V_{GS} @ 10V$, $I_D @ 500mA < 3\Omega$
- $R_{DS(ON)}$, $V_{GS} @ 4.5V$, $I_D @ 200mA < 4\Omega$
- Advanced Trench Process Technology
- High Density Cell Design For Ultra Low On-Resistance
- Very Low Leakage Current In Off Condition
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers: Relay, Displays, Memories, etc
- ESD Protected 2kV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0084 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^(Note 4)	I_D	300	mA
Pulsed Drain Current ^(Note 1)	I_{DM}	2000	
Power Dissipation	$T_A=25^\circ C$	500	mW
	Derate above $25^\circ C$	4	$mW/^\circ C$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal Resistance - Junction to Ambient ^(Note 3,4)	$R_{\theta JA}$	250	$^\circ C/W$



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=10\mu\text{A}$	60	-	-	V
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	1	-	2.5	
Drain-Source On-State Resistance	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=500\text{mA}$	-	-	3	Ω
		$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=200\text{mA}$	-	-	4	
Zero Gate Voltage Drain Current	I_{DSS}	$\text{V}_{\text{DS}}=60\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	± 10	
Forward Transconductance	g_{fs}	$\text{V}_{\text{DS}}=15\text{V}, \text{I}_D=250\text{mA}$	100	-	-	mS
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	$\text{V}_{\text{DS}}=15\text{V}, \text{I}_D=250\text{mA}, \text{V}_{\text{GS}}=5\text{V}$ ^(Note 1,2)	-	0.8	-	nC
Gate-Source Charge	Q_{gs}		-	0.35	-	
Gate-Drain Charge	Q_{gd}		-	0.2	-	
Input Capacitance	C_{iss}	$\text{V}_{\text{DS}}=25\text{V}, \text{V}_{\text{GS}}=0\text{V}, f=1\text{MHZ}$	-	35	-	pF
Output Capacitance	C_{oss}		-	13	-	
Reverse Transfer Capacitance	Crss		-	8	-	
Turn-On Delay Time	$\text{t}_{\text{d(on)}}$	$\text{V}_{\text{DD}}=30\text{V}, \text{I}_D=200\text{mA}, \text{V}_{\text{GS}}=10\text{V}, R_{\text{G}}=10\Omega$ ^(Note 1,2)	-	2.7	-	ns
Turn-On Rise Time	tr		-	19	-	
Turn-Off Delay Time	$\text{t}_{\text{d(off)}}$		-	15	-	
Turn-Off Fall Time	tf		-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_{s}	---	-	-	300	mA
Diode Forward Voltage	V_{SD}	$\text{I}_{\text{s}}=200\text{mA}, \text{V}_{\text{GS}}=0\text{V}$	-	0.82	1.3	V

NOTES:

1. Pulse width $\leq 300\text{us}$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

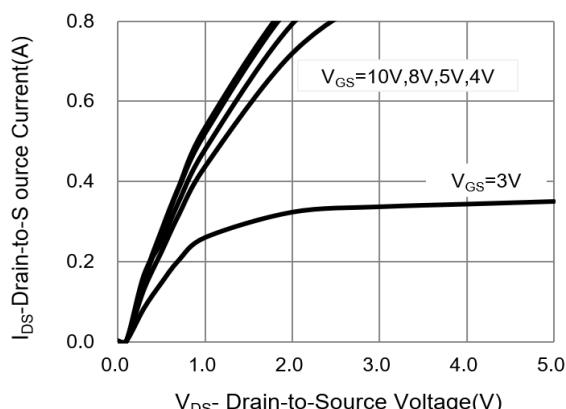


Fig.1 On-Region Characteristics

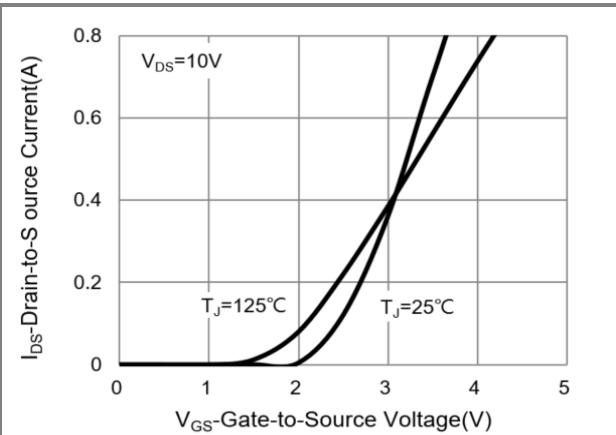


Fig.2 Transfer Characteristics

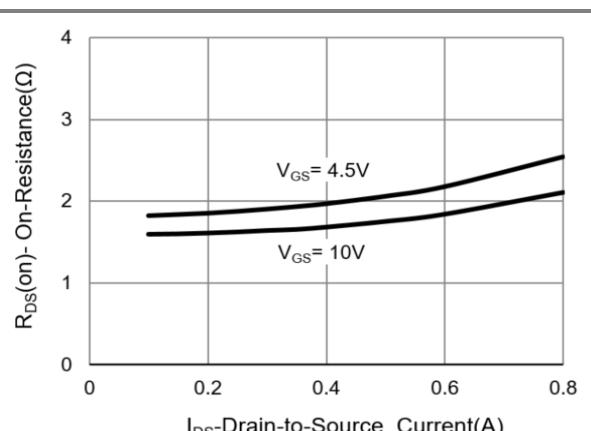


Fig.3 On-Resistance vs. Drain Current

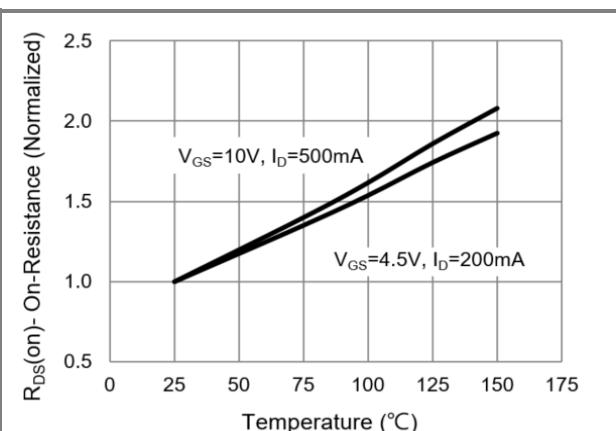


Fig.4 On-Resistance vs. Junction temperature

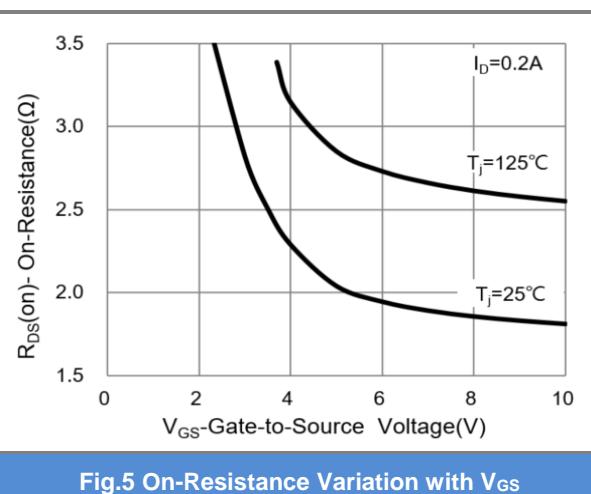


Fig.5 On-Resistance Variation with V_G

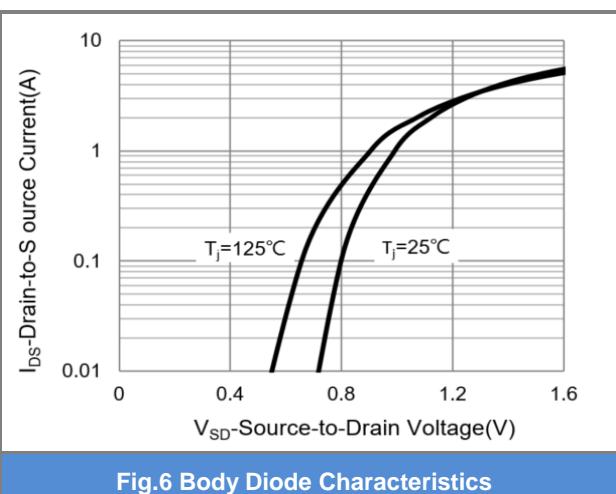
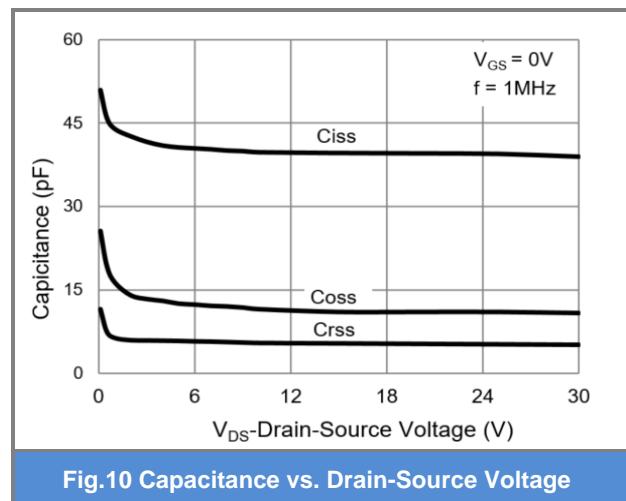
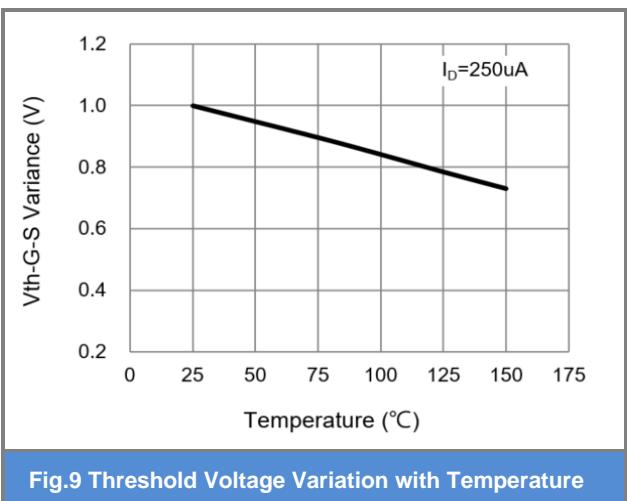
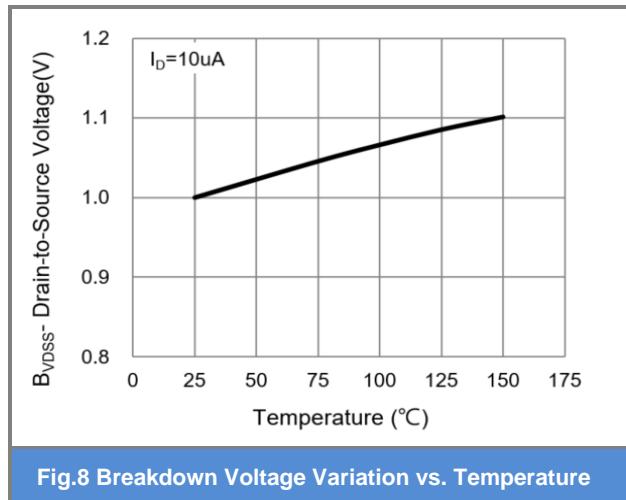
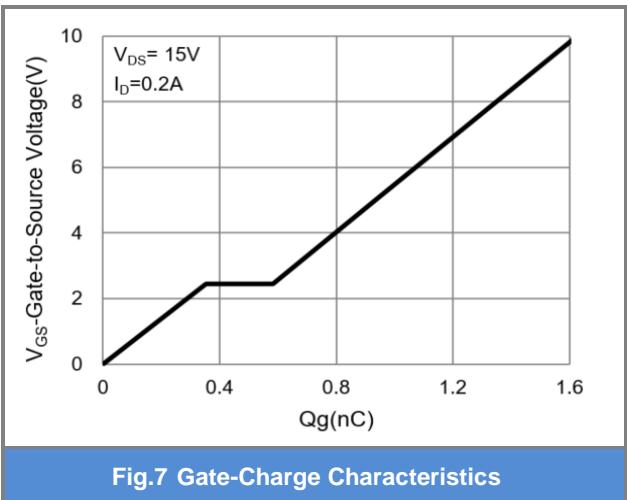


Fig.6 Body Diode Characteristics



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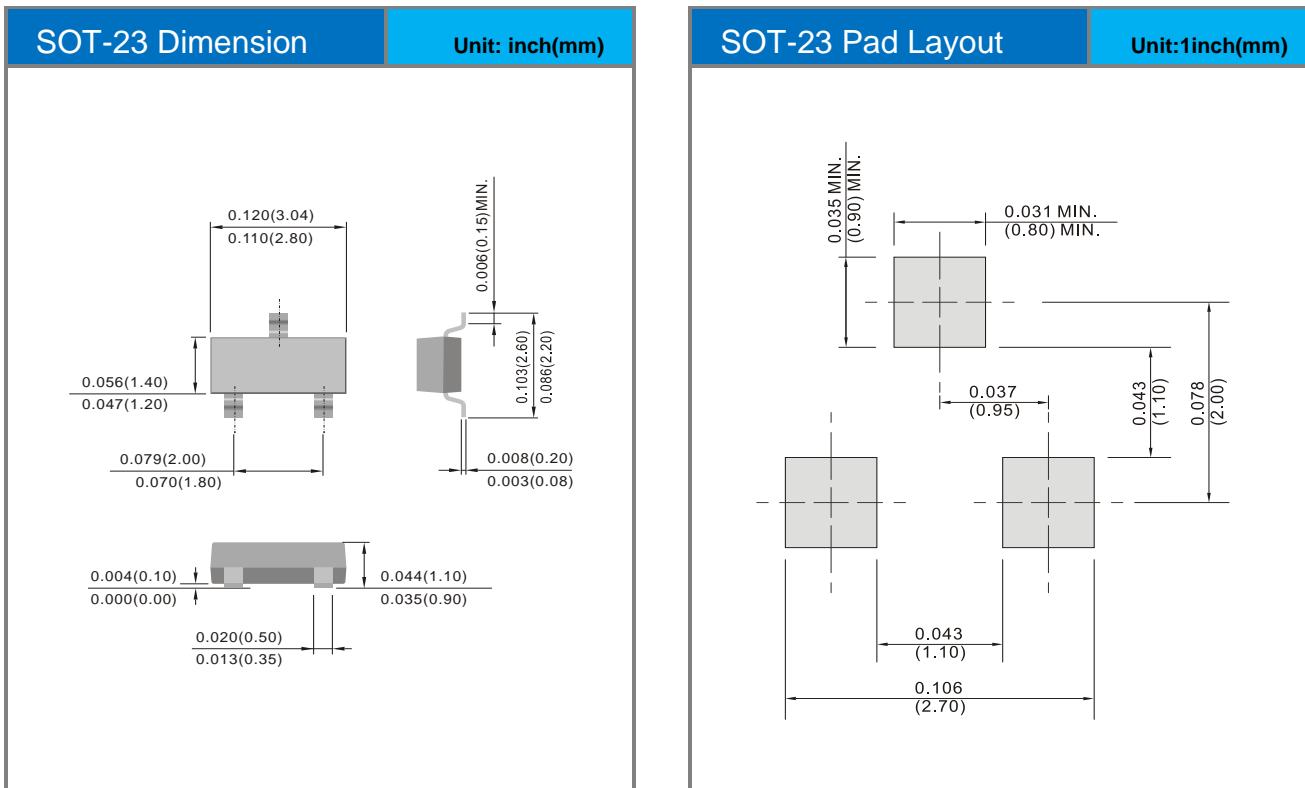


2N7002K

Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
2N7002K_R1_00501	SOT-23	3K pcs / 7" reel	K72	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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